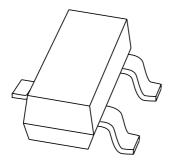
## DISCRETE SEMICONDUCTORS

## DATA SHEET



# **BAS16**High-speed diode

Product specification Supersedes data of 1999 May 26 2001 Oct 10





### **High-speed diode**

**BAS16** 

#### **FEATURES**

- Small plastic SMD package
- High switching speed: max. 4 ns
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 85 V
- Repetitive peak forward current: max. 500 mA.

#### **APPLICATIONS**

High-speed switching in hybrid thick and thin-film circuits.

#### **DESCRIPTION**

The BAS16 is a high-speed switching diode fabricated in planar technology, and encapsulated in a small SOT23 plastic SMD package.

#### **MARKING**

TYPE NUMBER	MARKING CODE <sup>(1)</sup>
BAS16	A6*

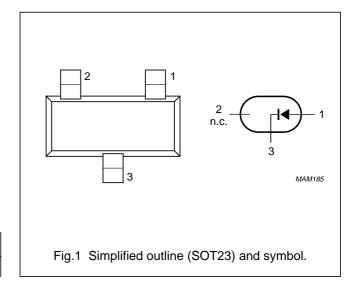
#### Note

1. \* = p : Made in Hong Kong.\* = t : Made in Malaysia.

\* = W : Made in China.

#### **PINNING**

PIN	DESCRIPTION	
1	anode	
2	not connected	
3	cathode	



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>RRM</sub>	repetitive peak reverse voltage		_	85	V
V <sub>R</sub>	continuous reverse voltage		_	75	٧
I <sub>F</sub>	continuous forward current	see Fig.2; note 1	_	215	mA
I <sub>FRM</sub>	repetitive peak forward current		_	500	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; T <sub>j</sub> = 25 °C prior to surge; see Fig.4			
		t = 1 μs	_	4	Α
		t = 1 ms	_	1	А
		t = 1 s	_	0.5	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; note 1	_	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>i</sub>	junction temperature		_	150	°C

#### Note

1. Device mounted on an FR4 printed-circuit board.

## High-speed diode

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#### **ELECTRICAL CHARACTERISTICS**

 $T_j = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V <sub>F</sub>	forward voltage	see Fig.3		
		I <sub>F</sub> = 1 mA	715	mV
		I <sub>F</sub> = 10 mA	855	mV
		I <sub>F</sub> = 50 mA	1	V
		I <sub>F</sub> = 150 mA	1.25	V
I <sub>R</sub>	reverse current	see Fig.5		
		V <sub>R</sub> = 25 V	30	nA
		V <sub>R</sub> = 75 V	1	μΑ
		V <sub>R</sub> = 25 V; T <sub>j</sub> = 150 °C	30	μΑ
		V <sub>R</sub> = 75 V; T <sub>j</sub> = 150 °C	50	μΑ
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 0; see Fig.6	1.5	pF
t <sub>rr</sub>	reverse recovery time	when switched from I <sub>F</sub> = 10 mA to	4	ns
		$I_R = 10 \text{ mA}$ ; $R_L = 100 \Omega$ ; measured at		
		I <sub>R</sub> = 1 mA; see Fig.7		
V <sub>fr</sub>	forward recovery voltage	when switched from $I_F = 10$ mA; $t_r = 20$ ns; see Fig.8	1.75	V

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-tp</sub>	thermal resistance from junction to tie-point		330	K/W
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	500	K/W

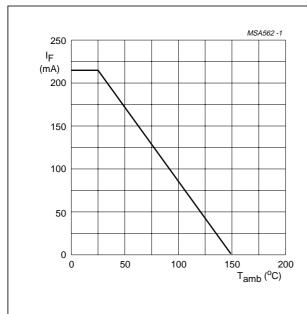
#### Note

1. Device mounted on an FR4 printed-circuit board.

## High-speed diode

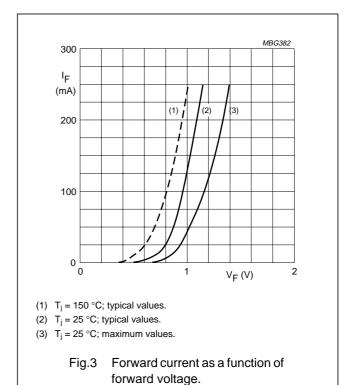
**BAS16** 

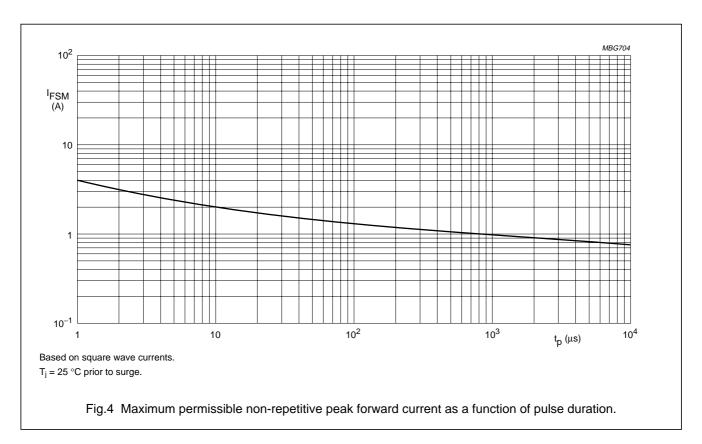
#### **GRAPHICAL DATA**



Device mounted on an FR4 printed-circuit board.

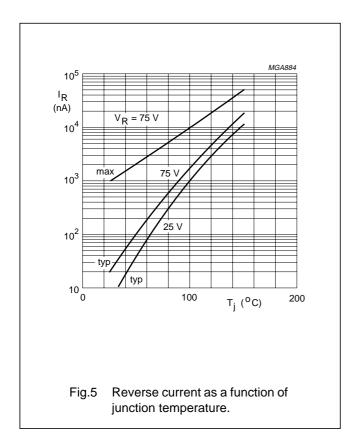
Fig.2 Maximum permissible continuous forward current as a function of ambient temperature.





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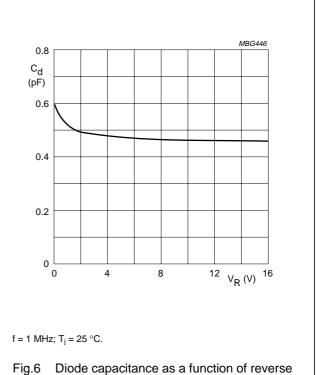
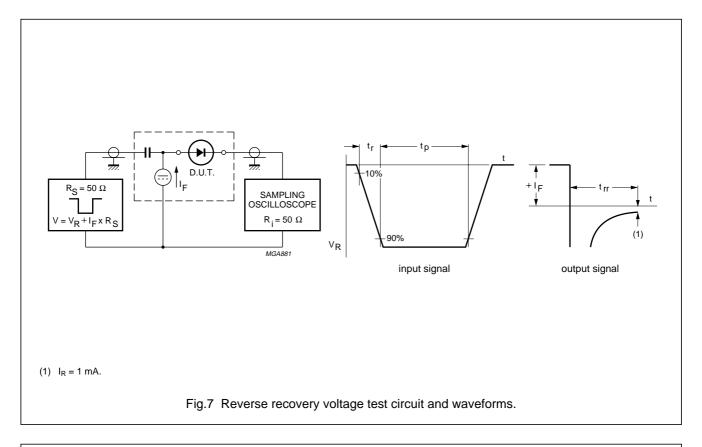
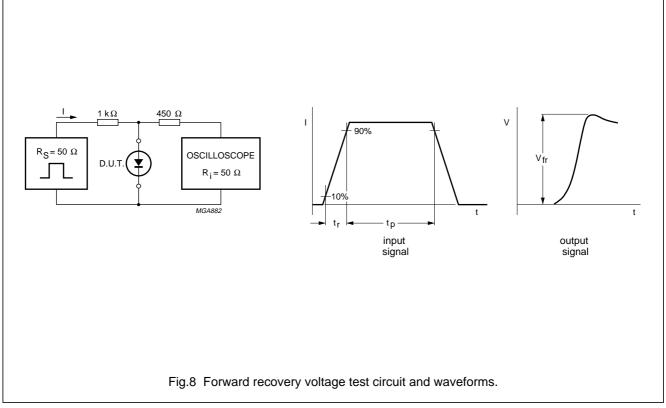


Fig.6 Diode capacitance as a function of reverse voltage; typical values.

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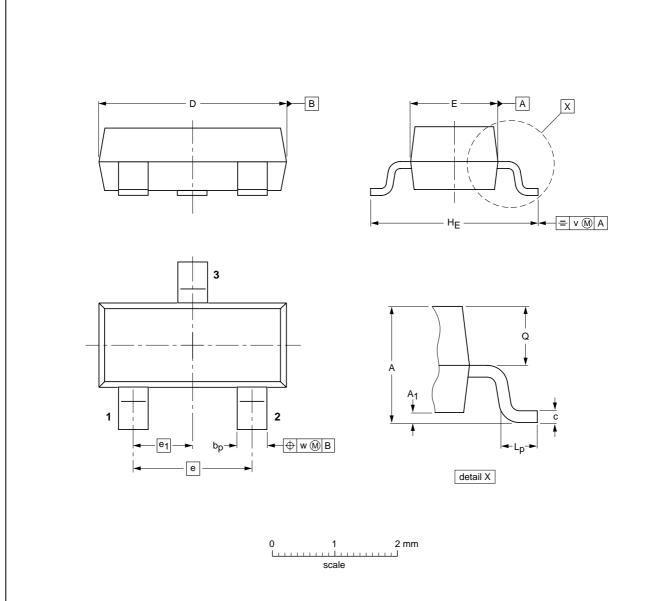
## High-speed diode

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#### **PACKAGE OUTLINE**

Plastic surface mounted package; 3 leads

SOT23



<b>DIMENSIONS</b> (mm are	the original dimensions)
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UNIT	Α	A <sub>1</sub> max.	bp	С	D	E	е	e <sub>1</sub>	HE	L <sub>p</sub>	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE	LINE REFERENCES		EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT23		TO-236AB				<del>-97-02-28-</del> 99-09-13

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DATA SHEET STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
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#### **Contact information**

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